

ProductID 310-FG-02 series

Bare Die (Flip chip form, Au Pad)

Typical Optical-Electrical Characteristics

 $(I_{F}=100 \text{mA}, T_{a}=25^{\circ}\text{C})$

Item	Symbol	Unit	310-FG-02-C		
			Min	Тур	Max
Peak Wavelength	λ _p	nm	305	310	315
Radiant Flux	Po	mW	-	24	-
Full Width at Half Maximum	⊿λ	nm	-	15	-
Forward Voltage	V _F	V	-	5.4	-

(*)Peak Wavelength Measurement tolerance is ±3nm.

(**)Radiant Flux Measurement tolerance is ±10%.

Specification and dimension are subject to change for improvement without notice.

Product ID, Physical dimensions and Sapmle photo 310-FG-02-C 310-FG-02-S0A Cathode 780 -1500-Unit:µm 13,00 780 586 750 ÷ 750 Anode Anode 160 200 246 Cathode Au Pad thickness: 3µm 31 540 310 2 WARNING - LEDs emit very strong UV radiation. · Do not look at the LED light with the naked eye or irradiate the skin.

To prevent UV radiation exposure, wear protective eyewear and protective equipment.
If LEDs are embedded in devices, please indicate warning labels against the UV light LED used.

DOWA Electronics Materials Co., Ltd.

UV radiation can harm your eyes and skin.

· Keep out of reach of children.

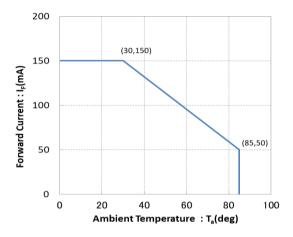


ProductID 310-FG-02 series Bare Die (Flip chip form, Au Pad)

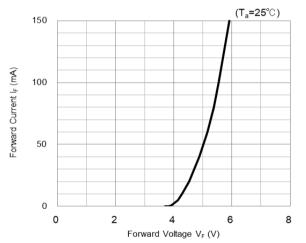
Absolute Maximum Ratings

ltem	Symbol	Unit	Value
Forward Current	I _F	mA	150
Junction Temperature	TJ	°C	90
Operating Temperature	T _{OPR}	°C	-30 ~ +85
Storage Temperature	T _{STR}	°C	-40 \sim +85 (No condensation)

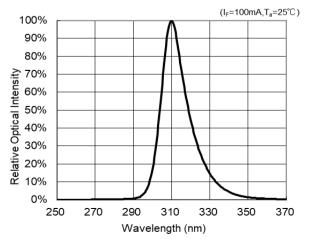
Derating Curve



Forward Voltage vs Forward Current



Spectrum



Forward Current vs Radiant Flux

